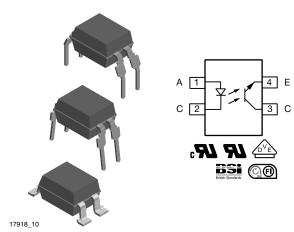


Vishay Semiconductors

Optocoupler, Phototransistor Output, High Temperature, 110 °C Rated



DESCRIPTION

The VO610A consists of a phototransistor optically coupled to a gallium arsenide infrared-emitting diode in a 4 pin plastic dual inline package.

AGENCY APPROVALS

- BSI: EN 60065:2002, EN 60950:2000
- DIN EN 60747-5-2 (VDE 0884)/DIN EN 60747-5-5 (pending), available with option 1
- FIMKO
- UL file no. E52744
- cUL tested to CSA 22.2 bulletin 5A

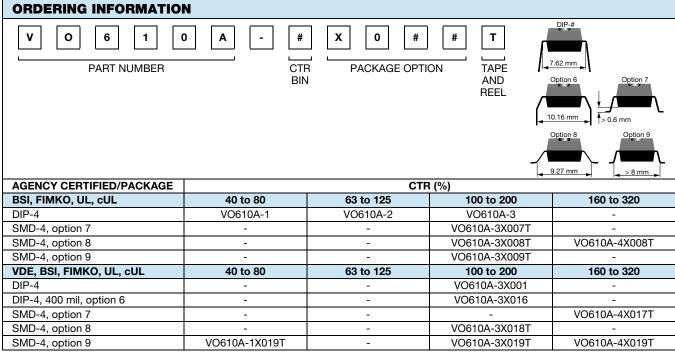
FEATURES

- CTR offered in 4 groups
- Isolation materials according to UL 94 V-0
- Pollution degree 2 (DIN/VDE 0110/resp. IEC 60664)
- Climatic classification 55/110/21 (IEC 60068 part 1)
- Temperature range 55 °C to + 110 °C
- Rated impulse voltage (transient overvoltage) $V_{\text{IOTM}} = 6 \text{ kV}_{\text{peak}}$
- Isolation test voltage (partial discharge test voltage)
 V_{pd} = 1.6 kV
- Rated isolation voltage (RMS includes DC) V_{IOWM} = 600 V_{RMS}
- Rated recurring peak voltage (repetitive) V_{IORM} = 850 V_{peak}
- Creepage current resistance according to VDE 0303/ IEC 60112 comparative tracking index: CTI ≥ 175
- Thickness through insulation ≥ 0.4 mm
- Compliant to RoHS Directive 2002/95/EC

APPLICATIONS

Circuits for safe protective separation against electrical shock according to safety class II (reinforced isolation):

- for appl. class I IV at mains voltage ≤ 300 V
- for appl. class I IV at mains voltage ≤ 600 V according to table 1 of IEC 60664-1, suitable for:
 - Switch-mode power supplies
 - Line receiver
 - Computer peripheral interface
 - Microprocessor system interface



Note

Rev. 1.6, 05-Dec-11

• Additional options may be possible, please contact sales office



www.vishay.com

Vishay Semiconductors

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
INPUT							
Reverse voltage		V_R	6	V			
Forward current		I _F	60	mA			
Forward surge current	t _p ≤ 10 μs	I _{FSM}	1.5	Α			
LED power dissipation	at 25 °C	P _{diss}	100	mW			
OUTPUT							
Collector emitter voltage		V _{CEO}	70	V			
Emitter collector voltage		V _{ECO}	7	V			
Collector current		I _C	50	mA			
Collector peak current	$t_p/T = 0.5, t_p \le 10 \text{ ms}$	I _{CM}	100	mA			
Output power dissipation	at 25 °C	P _{diss}	150	mW			
COUPLER							
Isolation test voltage (RMS)	t = 1 min	V _{ISO}	5000	V_{RMS}			
Operating ambient temperature range		T _{amb}	- 55 to + 110	°C			
Storage temperature range		T _{stg}	- 55 to + 125	°C			
Soldering temperature (1)	2 mm from case, ≤ 10 s	T _{sld}	260	°C			

Notes

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
 implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
 maximum ratings for extended periods of the time can adversely affect reliability.
- (1) Refer to reflow profile for soldering conditions for surface mounted parts (SMD). Refer to wave profile for soldering conditions for through hole parts (DIP).

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)									
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT			
INPUT	INPUT								
Forward voltage	$I_F = 50 \text{ mA}$	V _F		1.25	1.6	V			
Junction capacitance	$V_R = 0$, $f = 1$ MHz	C _j		50		pF			
OUTPUT									
Collector emitter voltage	$I_C = 1 \text{ mA}$	V_{CEO}	70			V			
Emitter collector voltage	$I_E = 100 \mu A$	V _{ECO}	7			V			
Collector emitter cut-off current	$V_{CE} = 20 \text{ V}, I_F = 0 \text{ A}$	I _{CEO}		10	100	nA			
COUPLER									
Collector emitter saturation voltage	$I_F = 10 \text{ mA}, I_C = 1 \text{ mA}$	V _{CEsat}			0.3	V			
Cut-off frequency	V_{CE} = 5 V, I_F = 10 mA, R_L = 100 Ω	f _c		110		kHz			
Coupling capacitance	f = 1 MHz	C _k		0.6		pF			

Note

 Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.



www.vishay.com

Vishay Semiconductors

CURRENT TRANSFER RATIO (T _{amb} = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT	
I _C /I _F	V _{CE} = 5 V, I _F = 1 mA	VO610A-1	CTR	13	30		%	
		VO610A-2	CTR	22	45		%	
		VO610A-3	CTR	34	70		%	
		VO610A-4	CTR	56	90		%	
	V _{CE} = 5 V, I _F = 10 mA	VO610A-1	CTR	40		80	%	
		VO610A-2	CTR	63		125	%	
		VO610A-3	CTR	100		200	%	
		VO610A-4	CTR	160		320	%	

SAFETY AND INSULATION RATED PARAMETERS							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Partial discharge test voltage - routine test	100 %, t _{test} = 1 s	V _{pd}	1.6			kV	
Partial discharge test voltage - lot test (sample test)	$t_{Tr} = 60 \text{ s}, t_{test} = 10 \text{ s},$ (see figure 2)	V _{pd}	1.3			kV	
Insulation resistance	V _{IO} = 500 V	R _{IO}	10 ¹²			Ω	
	V _{IO} = 500 V, T _{amb} = 100 °C	R _{IO}	10 ¹¹			Ω	
	V _{IO} = 500 V, T _{amb} = 150 °C (construction test only)	R _{IO}	10 ⁹			Ω	
Rated impulse voltage		V _{IOTM}			6	kV	
Max. working voltages	Recurring peak voltage	V _{IORM}	850			V _{peak}	
Forward current		I _{SI}			130	mA	
Power dissipation		P _{SO}			265	mW	
Safety temperature		T _{si}			150	°C	
Creepage distance			7.6			mm	

Note

 According to DIN EN 60747-5-2 (VDE 0884) (see figure 2). This optocoupler is suitable for safe electrical isolation only within the safety ratings. Compliance with the safety ratings shall be ensured by means of suitable protective circuits.

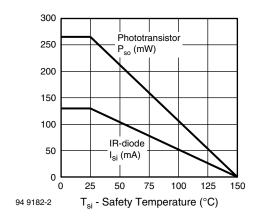


Fig. 1 - Derating Diagram

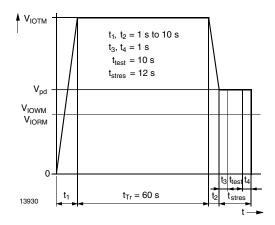


Fig. 2 - Test Pulse Diagram for Sample Test according to DIN EN 60747-5-2 (VDE0884)/DIN EN 60747-; IEC60747



Vishay Semiconductors

SWITCHING CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Delay time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega,$ (see figure 3)	t _d		3		μs	
Rise time	V_S = 5 V, I_C = 2 mA, R_L = 100 Ω , (see figure 3)	t _r		3		μs	
Fall time	V_S = 5 V, I_C = 2 mA, R_L = 100 Ω , (see figure 3)	t _f		4.7		μs	
Storage time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega,$ (see figure 3)	t _s		0.3		μs	
Turn-on time	V_S = 5 V, I_C = 2 mA, R_L = 100 Ω , (see figure 3)	t _{on}		6		μs	
Turn-off time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega,$ (see figure 3)	t _{off}		5		μs	
Turn-on time	$V_S = 5 \text{ V}, I_F = 10 \text{ mA}, R_L = 1 \text{ k}\Omega,$ (see figure 4)	t _{on}		9		μs	
Turn-off time	$V_S = 5 \text{ V}, I_F = 10 \text{ mA}, R_L = 1 \text{ k}\Omega,$ (see figure 4)	t _{off}		10		μs	

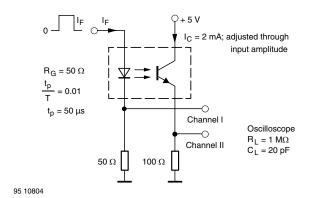


Fig. 3 - Test Circuit, Non-Saturated Operation

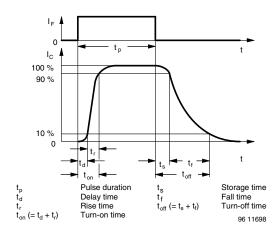


Fig. 5 - Switching Times

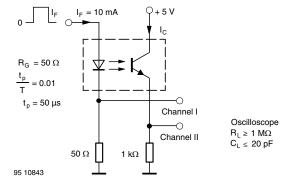
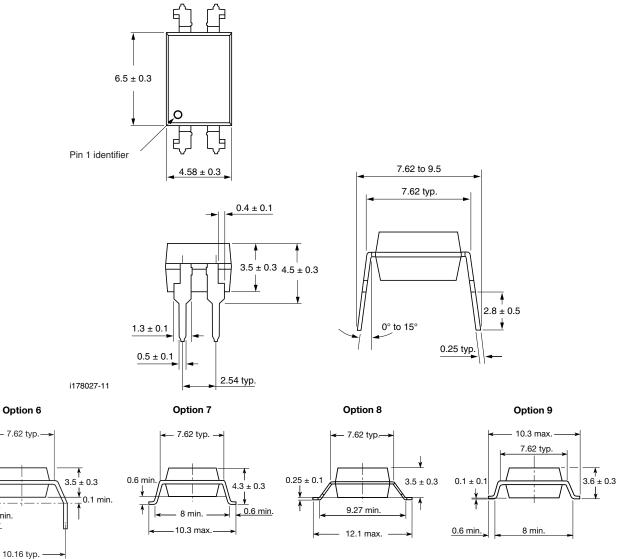


Fig. 4 - Test Circuit, Saturated Operation



Vishay Semiconductors

PACKAGE DIMENSIONS in millimeters

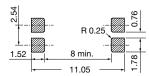


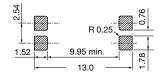


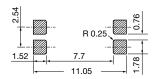
– 10.16 typ. -

2.7 min.

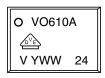
Option 6







PACKAGE MARKING



Note

- Only options 1, 7, and 8 are reflected in the package marking.
- The VDE logo is only printed on option 1 parts.
- Tape and reel suffix (T) is not part of the package marking.



Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk and agree to fully indemnify and hold Vishay and its distributors harmless from and against any and all claims, liabilities, expenses and damages arising or resulting in connection with such use or sale, including attorneys fees, even if such claim alleges that Vishay or its distributor was negligent regarding the design or manufacture of the part. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Material Category Policy

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.